

Contents

1	Fundamentals of Nucleation Theory	1
1.1	Thermodynamics of Phase Transition	4
1.2	Scenarios of Phase Transition	11
1.3	Laplacian Pressure and Gibbs–Thomson Effect	15
1.4	Contact Angle	18
1.5	Formation Energy	24
1.6	Adsorption and Thin Films	30
1.7	Growth Rates	38
1.8	Rate Equations of Nucleation Theory	43
1.9	Exact Solutions	47
1.10	Continuum Approximation	55
1.11	Stationary State	57
1.12	Stages of Nucleation-Condensation Process	64
2	Theoretical Description of Condensation Stages	75
2.1	Transformation to Invariant Size	77
2.2	Nucleation Stage	81
2.3	Nucleation Modes	88
2.4	Green Function at the Growth Stage	95
2.5	Absence of Fluctuation-Induced Spreading at the Nucleation Stage	100
2.6	Time Evolution of Size Spectrum	101
2.7	Asymptotic Growth Stage	112
2.8	Ostwald Ripening	115
2.9	Tailoring the Size Distribution	122
2.10	Kolmogorov–Johnson–Mehl–Avrami Model	129
2.11	Three-Dimensional Thin Films	133
2.12	Growth Rate of a Crystal Facet of Arbitrary Size	138
2.13	Irreversible Growth	143
2.14	Formation of Peptide Chains	156
2.15	Open Irreversible Systems	161
3	Self-Induced Islands in Lattice Mismatched Systems	167
3.1	Size Quantization in Semiconductor Nanostructures	170

3.2	Stranski-Krastanow Growth	178
3.3	Elastic Relaxation in Nanostructures	190
3.4	Growth Scenarios and Preferred Aspect Ratio	197
3.5	Formation Energy of Stranski-Krastanow Islands	207
3.6	Nucleation Stage and Critical Thickness	213
3.7	Growth of Stranski-Krastanow Islands	219
3.8	Modeling of Size Distribution	223
3.9	Role of Surface Steps	225
3.10	Subcritical Quantum Dots	228
3.11	Kinetically Controlled Engineering of Quantum Dot Ensembles	231
3.12	Theory and Experiment: InAs/GaAs System	235
3.13	Theory and Experiment: Ge/Si System	243
3.14	III-V Nanoneedles and Nanopillars	249
3.15	Growth Kinetics of GaAs Nanoneedles	260
3.16	Growth Properties of Co Nanoislands on $\text{CaF}_2/\text{Si}(111)$	265
4	Vapor-Liquid-Solid Growth of Nanowires	275
4.1	Vapor-Liquid-Solid Growth Mechanism	277
4.2	Alternative Growth Mechanisms	298
4.3	Role of Size-Dependent Effects	304
4.4	Role of Surface Energies	310
4.5	Triple Phase Line Nucleation	315
4.6	Non-planar Growth Interfaces	318
4.7	Adsorption-Induced Growth	323
4.8	Diffusion-Induced Growth	332
4.9	Simplified Growth Equations	342
4.10	Self-Consistent Growth Models	347
4.11	Length—Radius Dependences	355
4.12	Temperature Conditions for the VLS Growth	369
4.13	Growth Chronology of a Single InPAs Nanowire	379
4.14	Non-linear Effects in Nanowire Growth	384
4.15	Narrowing the Length Distribution of Ge Nanowires	390
5	Special Topics of Nanowire Growth and Morphology	397
5.1	Axial Nanowire Heterostructures	399
5.2	Nanowires on Lattice Mismatched Substrates	403
5.3	Core-Shell Nanowire Heterostructures	410
5.4	Cylinder-to-Cone Shape Modification	416
5.5	Growth Modeling of CdTe Nanowires	427
5.6	Nucleation Statistics	430
5.7	Self-Regulated Pulsed Nucleation in Catalyzed Nanowires	435
5.8	Boron Distribution in Si Nanowire	442
5.9	Ga-catalyzed GaAs Nanowires	448

5.10	Self-Induced GaN Nanowires	456
5.11	Nucleation of GaN Nanowires	463
5.12	Scaling Growth Kinetics	471
5.13	Vertical Growth Rate of GaN Nanowires	476
5.14	Cooperative Effects in Nanowire Growth	482
5.14.1	Shadow Effect	483
5.14.2	Re-emission Assisted Growth of InSb-InAs Nanowires	488
5.15	Chemical Potentials for Au-assisted VLS Growth of III-V Nanowires	493
6	Crystal Structure of III-V Nanowires	499
6.1	Crystal Structures of III-V Materials	501
6.2	Experimental Observations of Polytypism	509
6.3	Surface Energies of Nanowire Sidewalls	515
6.4	Equilibrium Radius of Zincblende-Wurtzite Transition	523
6.5	Kinetic Theory of Wurtzite Phase Formation	526
6.6	Further Development of Kinetic Approach	532
6.7	Kinetic Radius of Structural Transition	538
6.8	Crystal Phase Engineering	541
6.9	Benefits of High Growth Rate	553
6.10	Zincblende Structure of Ga-catalyzed GaAs Nanowires	559
6.11	Wetting Mode of VLS Growth	563
6.12	Wurtzite Structure of III-V Nanoneedles	568
	References	573
	Index	591